

248634US2DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF: :

HIROYUKI KOBAYASHI ET AL :

SERIAL NO: NEW DIVISIONAL APPLN. :

FILED: HEREWITH :

FOR: SEMICONDUCTOR MEMORY DEVICE

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VA 22313

SIR:

Prior to examination on the merits, please amend the above-identified divisional application as follows:

**Amendment to the Specification** begins on page 2.

**Amendments to the Claims** begin on page 3 of this paper.

**Remarks/Arguments** begin on page 6 of this paper.